

# HAT2022R

Silicon N Channel Power MOS FET  
High Speed Power Switching

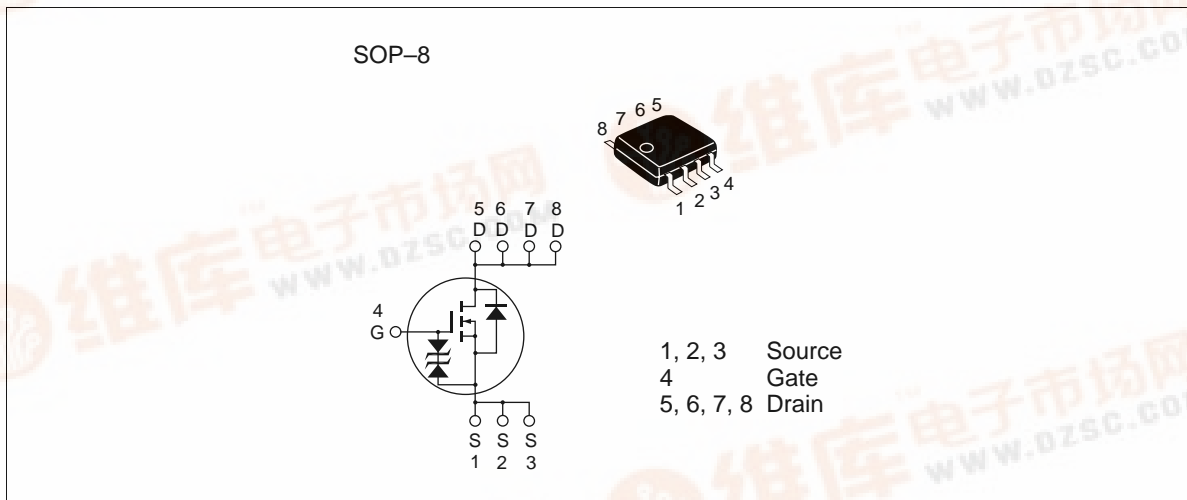
# HITACHI

ADE-208-440 J (Z)  
11th Edition  
February 1999

## Features

- Low on-resistance
- Capable of 4 V gate drive
- Low drive current
- High density mounting

## Outline



## HAT2022R

### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	30	V
Gate to source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	$I_D$	11	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	88	A
Body-drain diode reverse drain current	$I_{DR}$	11	A
Channel dissipation	Pch <sup>Note2</sup>	2.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	- 55 to + 150	°C

Note: 1. PW ≤ 10μs, duty cycle ≤ 1 %

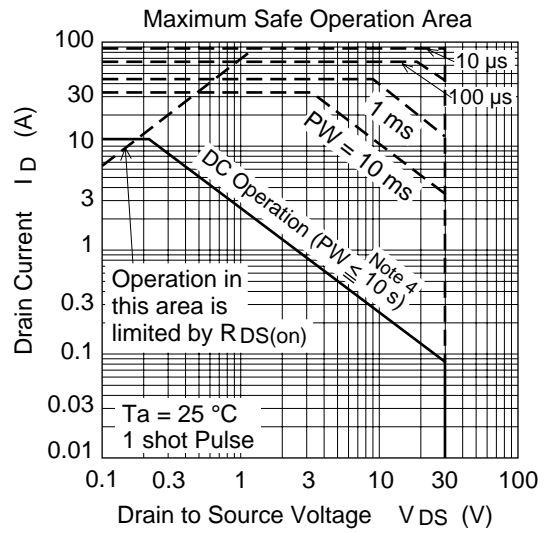
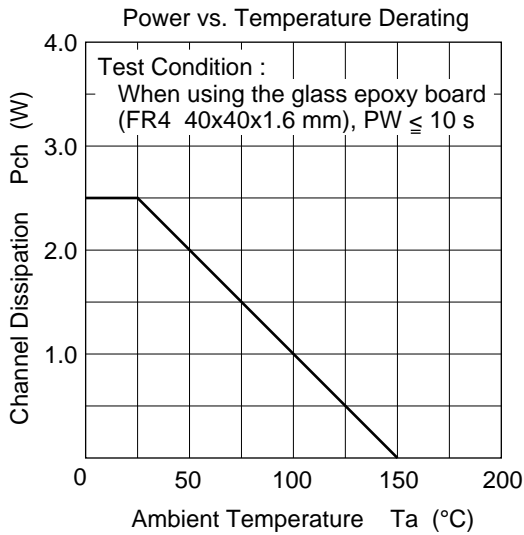
2. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW ≤ 10s

### Electrical Characteristics (Ta = 25°C)

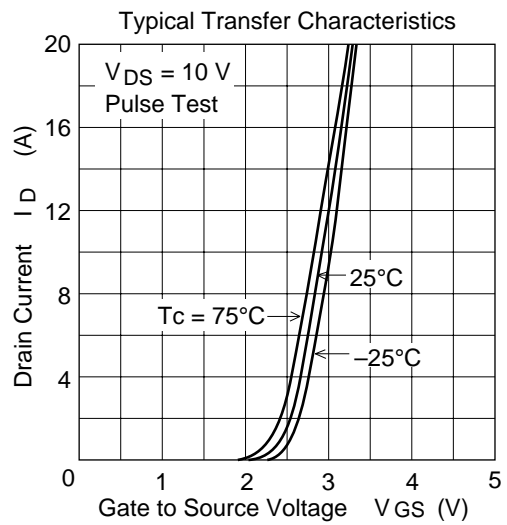
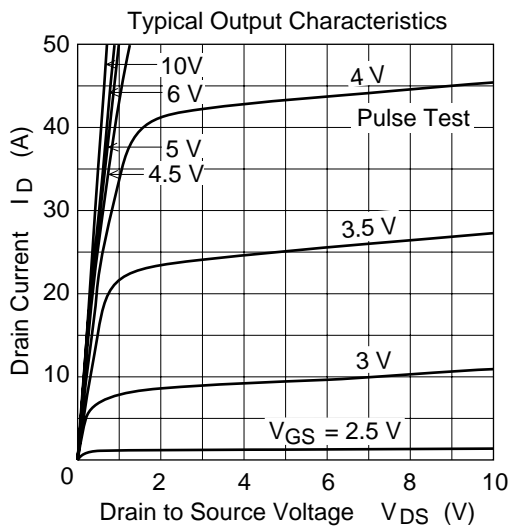
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	$\pm 20$	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$ , $V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 10$	μA	$V_{GS} = \pm 16 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	10	μA	$V_{DS} = 30 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.012	0.015	Ω	$I_D = 6 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note3</sup>
	$R_{DS(on)}$	—	0.017	0.025	Ω	$I_D = 6 \text{ A}$ , $V_{GS} = 4 \text{ V}$ <sup>Note3</sup>
Forward transfer admittance	$ y_{fs} $	12	18	—	S	$I_D = 6 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note3</sup>
Input capacitance	Ciss	—	1450	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	Coss	—	950	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	380	—	pF	f = 1MHz
Turn-on delay time	$t_{d(on)}$	—	60	—	ns	$V_{GS} = 4 \text{ V}$ , $I_D = 6 \text{ A}$
Rise time	$t_r$	—	450	—	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	80	—	ns	
Fall time	$t_f$	—	160	—	ns	
Body–drain diode forward voltage	$V_{DF}$	—	0.8	1.3	V	IF = 11 A, $V_{GS} = 0$ <sup>Note3</sup>
Body–drain diode reverse recovery time	$t_{rr}$	—	70	—	ns	IF = 11 A, $V_{GS} = 0$ diF/ dt = 20 A/μs

Note: 3. Pulse test

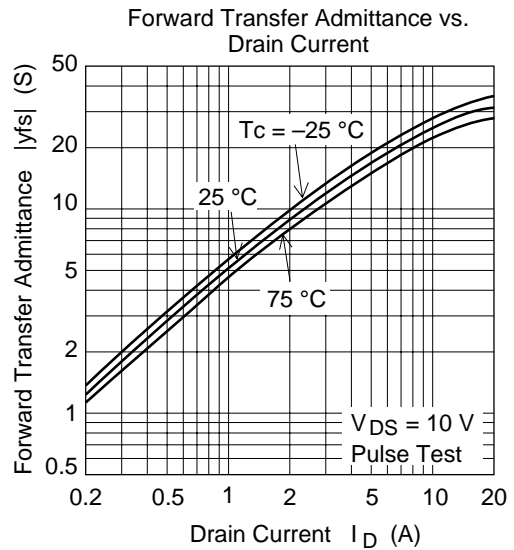
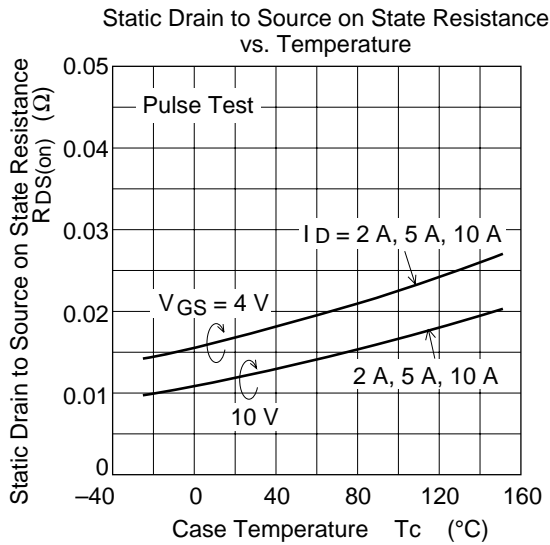
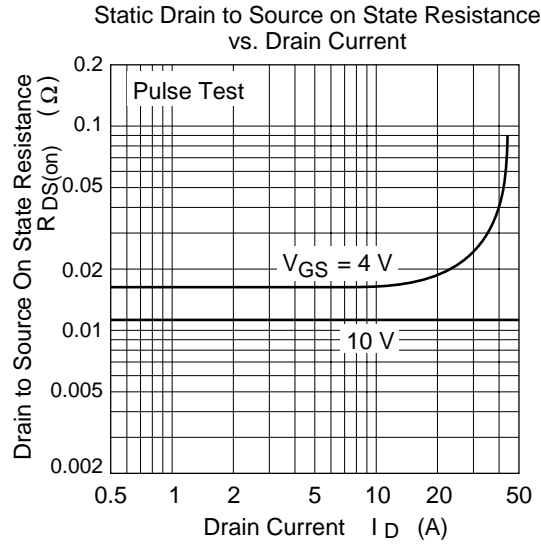
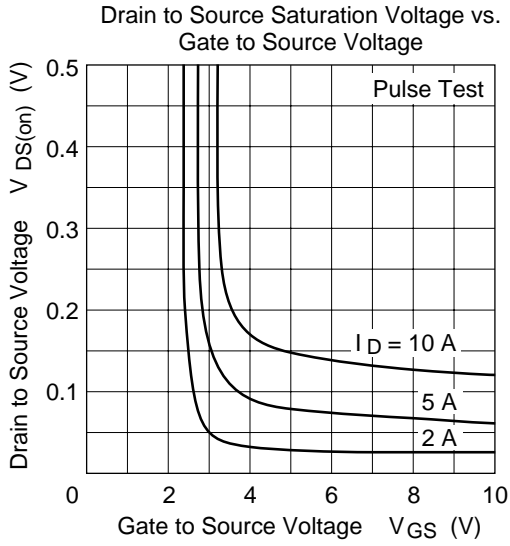
Main Characteristics

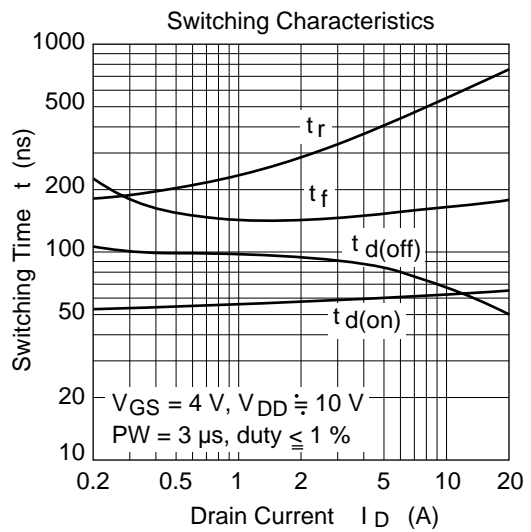
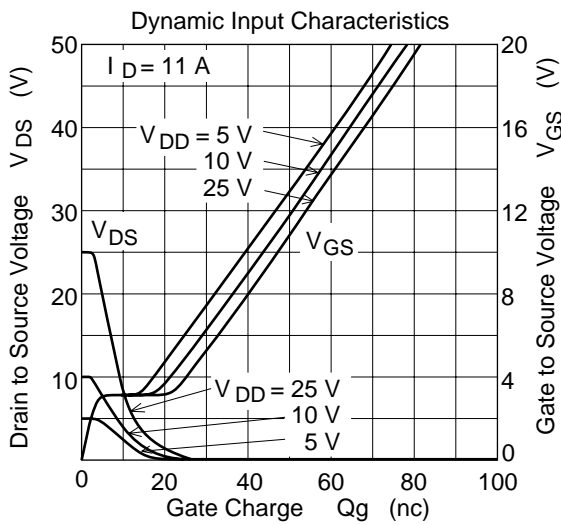
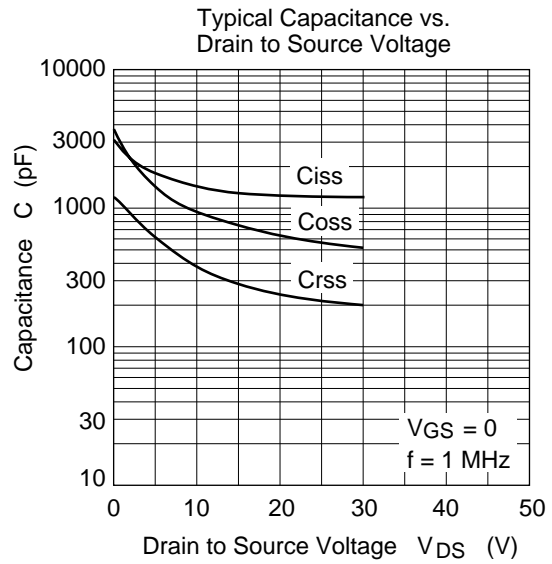
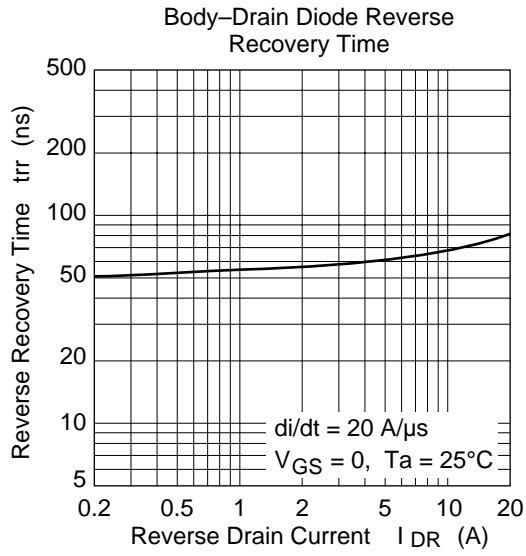


Note 4 :  
When using the glass epoxy board (FR4 40x40x1.6 mm)

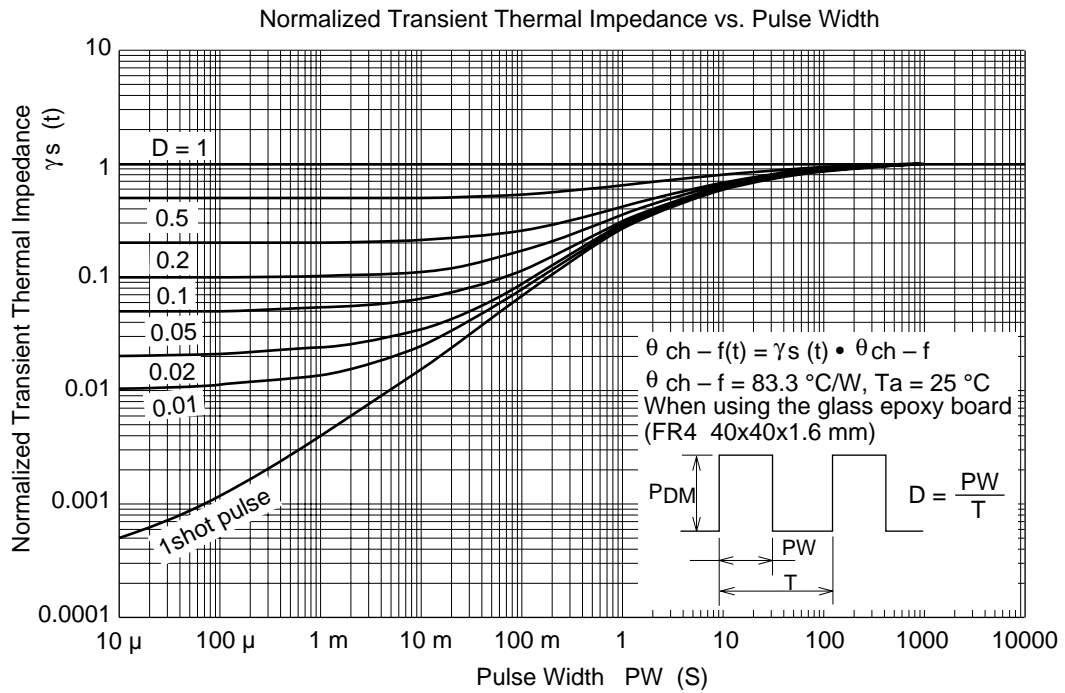
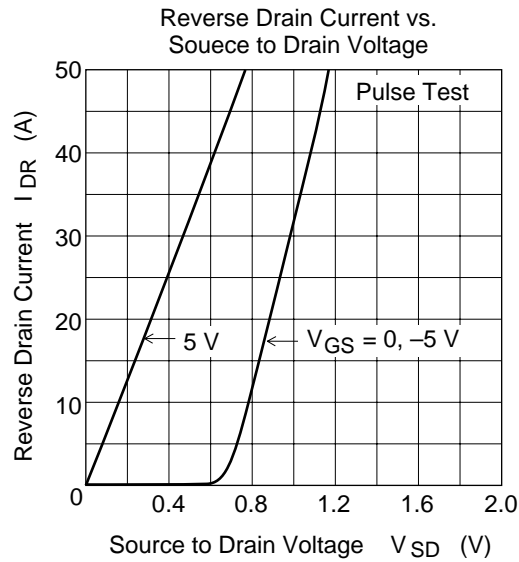


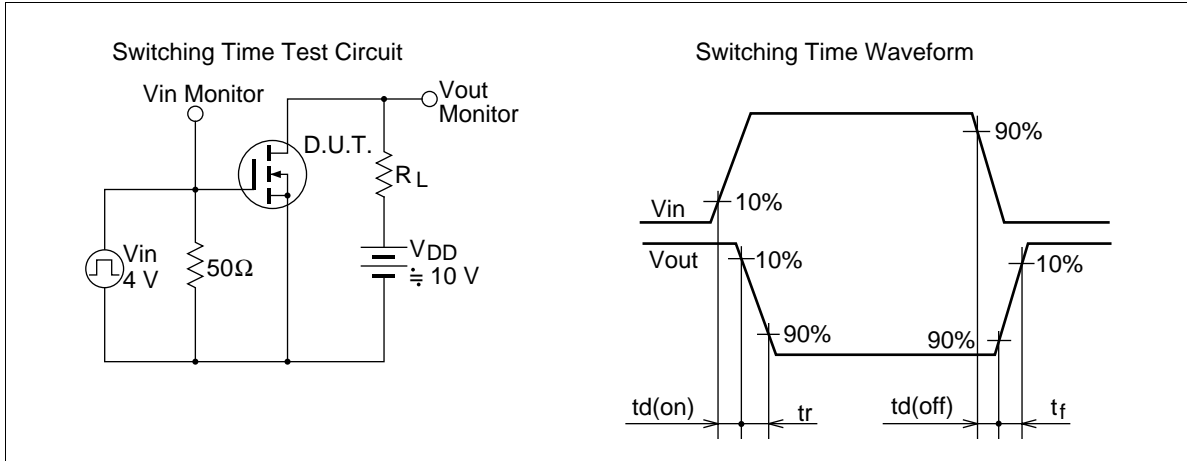
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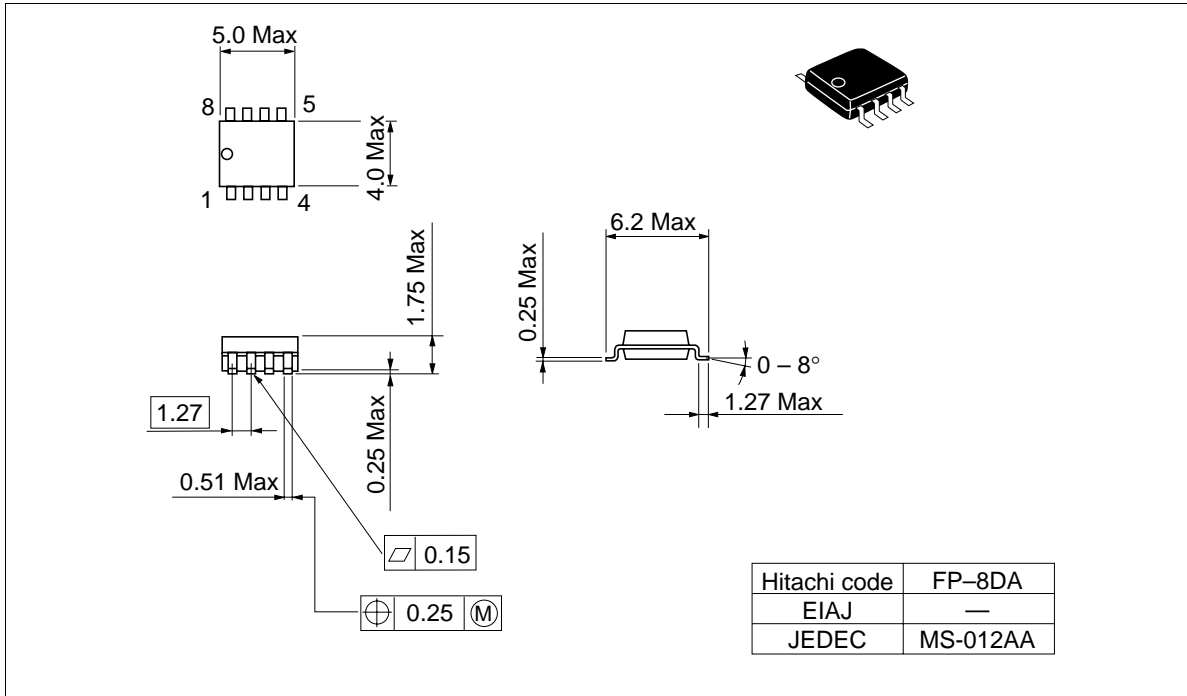




# HAT2022R

## Package Dimensions

Unit: mm





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